



500V N-Channel MOSFET

Voltage

500 V

Current

13 A

Features

- R_{DS(ON)}, V_{GS}@10V,I_D@6.5A<0.52Ω
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

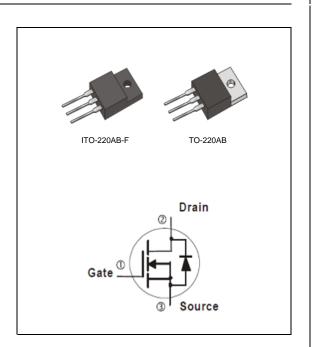
Mechanical Data

• Case: TO-220AB, ITO-220AB-F Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• TO-220AB Approx. Weight: 0.067 ounces, 1.9 grams

• ITO-220AB-F Approx. Weight: 0.068 ounces, 2 grams



Maximum Ratings and Thermal Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER		SYMBOL	TO-220AB	ITO-220AB-F	UNITS
Drain-Source Voltage		V_{DS}	500	V	
Gate-Source Voltage		V_{GS}	<u>+</u> 30		V
Continuous Drain Current		I _D	13		А
Pulsed Drain Current		I _{DM}	52		А
Single Pulse Avalanche Energy (Note 1)		E _{AS}	824		mJ
Power Dissipation	T _C =25°C	P _D	190	51	W
	Derate above 25°C		1.52	0.41	W/°C
Operating Junction and		T_J, T_{STG}			0.0
Storage Temperature Range			-55~1	°C	
Typical Thermal resistance					
- Junction to Case		$R_{ heta JC}$	0.66	2.45	°C/W
- Junction to Ambient		$R_{ heta JA}$	62.5	120	

Limited only By Maximum Junction Temperature





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V,I _D =250uA	500	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250uA$	2	3.1	4	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V,I _D =6.5A	-	0.44	0.52	Ω
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =500V,V _{GS} =0V	-	0.02	1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 30V,V _{DS} =0V	-	<u>+</u> 10	<u>+</u> 100	nA
Diode Forward Voltage	V_{SD}	I _S =13A,V _{GS} =0V	-	0.9	1.4	V
Dynamic ^(Note 4)						
Total Gate Charge	Q_g	V 400V I 40A	-	28	-	
Gate-Source Charge	V _{DS} =400V, I _D =13A, V _{GS} =10V (Note 2,3)		-	8.2	-	nC
Gate-Drain Charge	Q_{gd}	V _{GS} =10V	-	9.6	-	
Input Capacitance	Ciss	Ciss		1435	-	
Output Capacitance	Coss	$V_{DS}=25V, V_{GS}=0V,$	-	180	-	pF
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	5	-	
Turn-On Delay Time	td _(on)	V _{DD} =250V, I _D =13A,	-	14	-	ns
Turn-On Rise Time	t _r	$R_G=25\Omega$ (Note 2,3)	-	30	-	
Turn-Off Delay Time	td _(off)		-	36	-	
Turn-Off Fall Time	t _f		-	29	-	
Drain-Source Diode						
Maximum Continuous Drain-Source			-	-	13	А
Diode Forward Current	l _S					
Maximum Pulsed Drain-Source					52	_
Diode Forward Current	I _{SM}		-	-	52	A
Reverse Recovery Time	trr	V _{GS} =0V, I _S =13A	-	537	-	ns
Reverse Recovery Charge	Qrr	dI _F / dt=100A/us (Note 2)	-	5.3	-	uC

NOTES:

- 1. L=30mH, I_{AS} =7.15A, V_{DD} =50V, R_{G} =25 ohm, Starting T_{J} =25 $^{\circ}$ C
- 2. Pulse width<a>300us, Duty cycle<a>2%
- 3. Essentially independent of operating temperature typical characteristics.
- 4. Guaranteed by design, not subject to production testing





TYPICAL CHARACTERISTIC CURVES

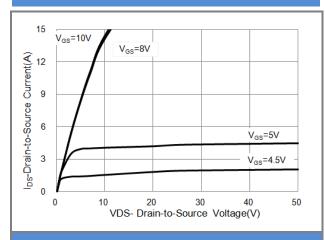


Fig.1 Output Characteristics

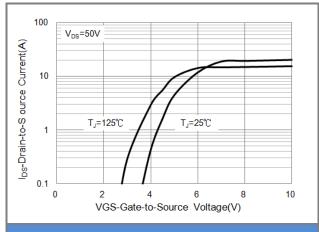


Fig.2 Transfer Characteristics

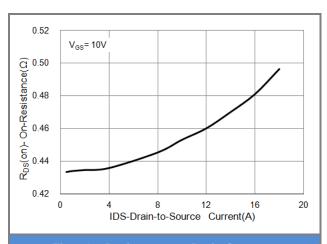


Fig.3 On-Resistance vs. Drain Current

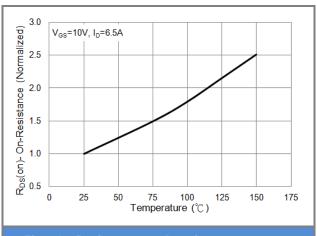
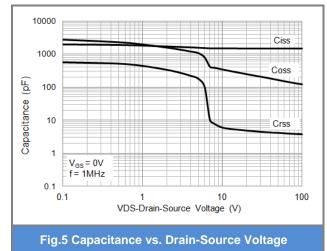
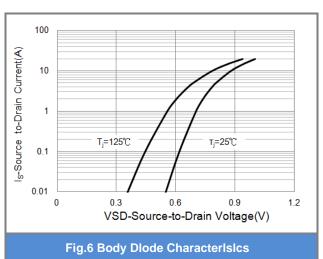


Fig.4 On-Resistance vs. Junction temperature









TYPICAL CHARACTERISTIC CURVES

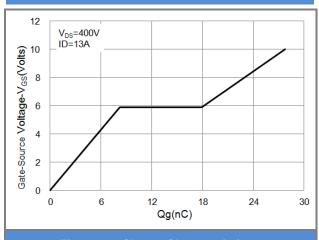


Fig.7 Gate-Charge Characteristics

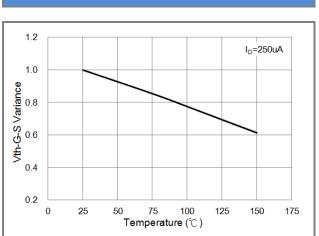


Fig.9 Threshold Voltage Variation with Temperature

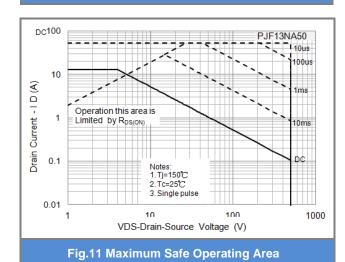


Fig.8 Breakdown Voltage Variation vs.Temperature

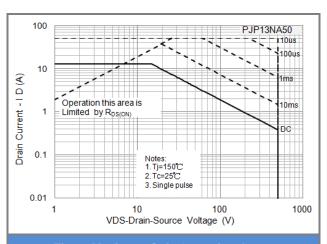


Fig.10 Maximum Safe Operating Area





TYPICAL CHARACTERISTIC CURVES

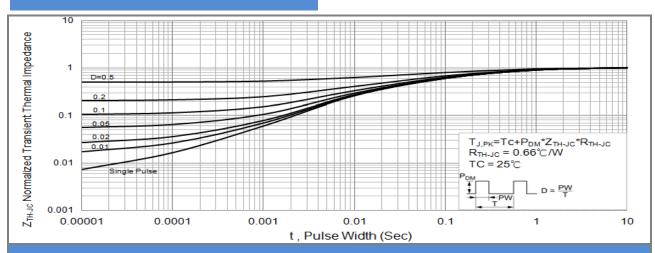


Fig.13 PJP13NA50 Normalized Transient Thermal Impedance vs. Pulse Width

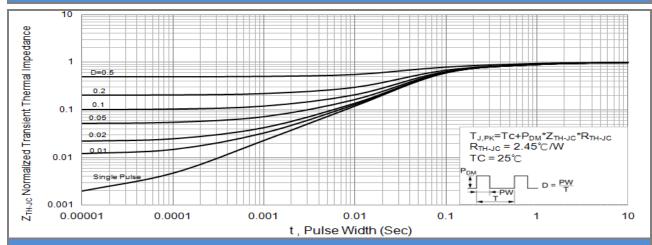
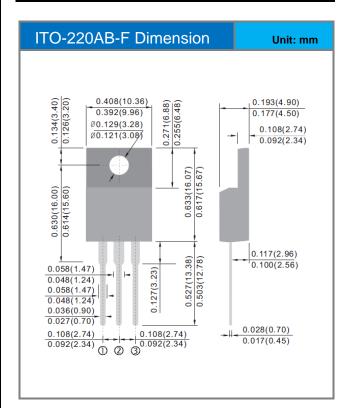


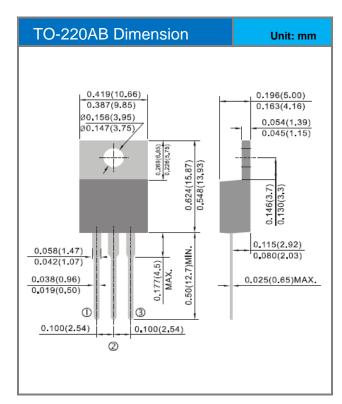
Fig.14 PJF13NA50 Normalized Transient Thermal Impedance vs. Pulse Width





Packaging Information









PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJP13NA50_T0_00001	TO-220AB	50pcs / Tube	P13NA50	Halogen free
PJF13NA50_T0_00001	ITO-220AB-F	50pcs / Tube	F13NA50	Halogen free





Disclaimer

- Reproducing and modifying information of the document is prohibited without permission from Panjit International Inc..
- Panjit International Inc. reserves the rights to make changes of the content herein the document anytime without notification. Please refer to our website for the latest document.
- Panjit International Inc. disclaims any and all liability arising out of the application or use of any product including damages incidentally and consequentially occurred.
- Panjit International Inc. does not assume any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.
- Applications shown on the herein document are examples of standard use and operation. Customers are
 responsible in comprehending the suitable use in particular applications. Panjit International Inc. makes no
 representation or warranty that such applications will be suitable for the specified use without further testing or
 modification.
- The products shown herein are not designed and authorized for equipments requiring high level of reliability or relating to human life and for any applications concerning life-saving or life-sustaining, such as medical instruments, transportation equipment, aerospace machinery et cetera. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Panjit International Inc. for any damages resulting from such improper use or sale.
- Since Panjit uses lot number as the tracking base, please provide the lot number for tracking when complaining.